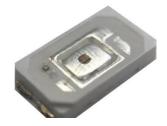


Features

- 5630 IR VCSEL
- ROHS and REACH Compliant
- ESD(HBM) 8KV

Applications

- Industrial facility applications
- Consumer Mobile
- Automotive Interior & Exterior
- 3D Sensing(TOF, Structure Light)
- Bio recognition



Description

The INV-P53CTRIR is a low-power IR VCSEL. It is a SMD type package which can be used in various applications.

Recommended Solder Pattern

(Suggest Stencil t=0.12 mm)

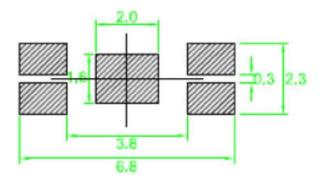
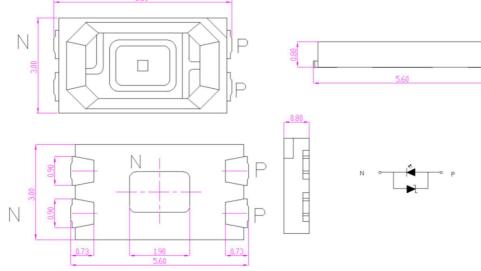


Figure 1. INV-P53CTRIR Solder Pattern



Package Dimensions in mm

Figure 2. INV-P53CTRIR Package Dimensions

*Note

All dimensions are in millimeters. Tolerance is ±0.1mm unless other specified.



Absolute Maximum Rating at 25°C (Note 1)

| Product | I _{FP} (mA) max | Pd(W) max | V _R (V) Typ. | T _j (°C) Typ. | T _{ST} (°C) | Rth (°C/W) | Soldering Temp. T _{sol} (°C) | esd HBM (V) |
|--------------|-----------------------------|--------------|----------------------------|-----------------------------|----------------------|------------|--|-------------|
| INV-P53CTRIR | 240 | 0.56 | -5 | 110 ºC | -40°C~+120°C | 60 | 260 °C | 8000 |

Notes

- 1. For other ambient, limited setting of current will depend on de-rating curves.
- 2. D=0.01s duty 1/10.
- 3. When drive on maximum current , Tj must be kept below $110^\circ\!\!\mathbb{C}$
- 4. Viewing angle(2 θ 1/2) ± 10°

Electrical Characteristics $T_A = 25^{\circ}C$ (Note 1)

| Product | V _F (V)@200mA | | Radiometric Power (mW) @200mA | | Peak Wavelength (nm) | | Ι _R (μA) | View Angle |
|--------------|--------------------------|-----|----------------------------------|-----|-------------------------|-----|---------------------|-------------------|
| | min | max | min | max | min | max | max | 2 heta 1/2 |
| INV-P53CTRIR | 1.8 | 3.0 | 120 | 160 | 840 | 860 | 3 | 30 |

*Notes

- 1. Performance guaranteed only under conditions listed in above tables.
- 2. Viewing angle $(2\theta 1/2) \pm 10^{\circ}$

ESD Precaution

ATTENTION: Electrostatic Discharge (ESD) protection



The symbol above denotes that ESD precaution is needed. ESD protection for GaP and AlGaAs based chips is necessary even though they are relatively safe in the presence of low static-electric discharge. Parts built with AlInGaP, GaN, or/and InGaN based chips are STATIC SENSITIVE devices. ESD precaution must be taken during design and assembly. If manual work or processing is needed, please ensure the device is adequately protected from ESD during the process.

Please be advised that normal static precautions should be taken in the handling and assembly of this device to prevent damage or degradation which may be induced by electrostatic discharge (ESD).



Binning Definition (Binning@200mA)

Power Bin

| Bin Code | Min. | Max. | Unit |
|----------|------|------|------|
| P84 | 120 | 160 | mW |

Wavelength Bin

| Bin Code | Min. | Max. | Unit |
|----------|------|------|------|
| W84 | 840 | 860 | nm |

Voltage Bin

| Bin Code | Min. | Max. | Unit |
|----------|------|------|------|
| V1 | 1.8 | 2.2 | |
| V2 | 2.2 | 2.6 | V |
| V3 | 2.6 | 3.0 | |

*Notes:

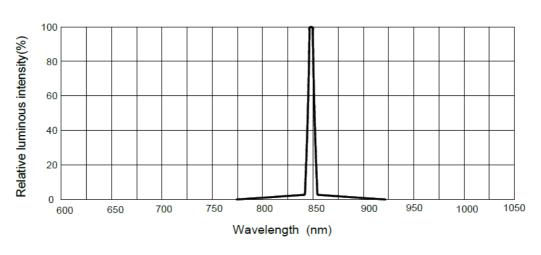
1. Radiometric Power (Po) ±10%.

2. Wavelength (Wp) ±2.0nm

3. Forward voltage (V_F) ±0.12V

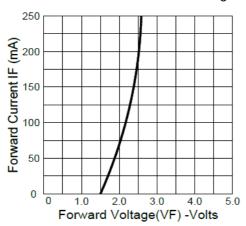


Electronic-Optical Characteristics

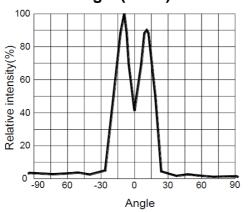


Spectrum Distribution

Forward Current VS. Forward Voltage



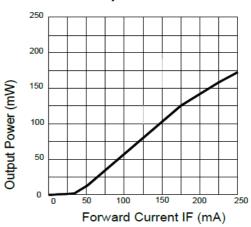
Beam angle (201/2) 30D



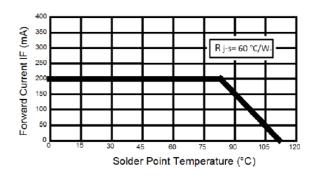


Viewing angle $(2\theta 1/2) \pm 10^{\circ}$

Luminous Intensity VS. Forward Current



Thermal Design for De-rating

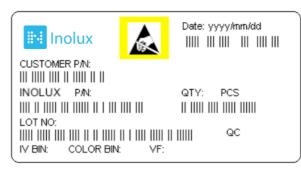




Ordering Information

| Orderable | Peak | Radiometric I @200 | | | • • • | Viewing | |
|--------------|--------------------|-----------------------|-----|-----|-------|---------|--|
| Part Number | Wavelength (nm) | Min | Max | Min | Max | Angle | |
| INV-P53CTRIR | 840-860 | 120 | 160 | 1.8 | 3.0 | 30° | |

Label Specifications



Inolux P/N:

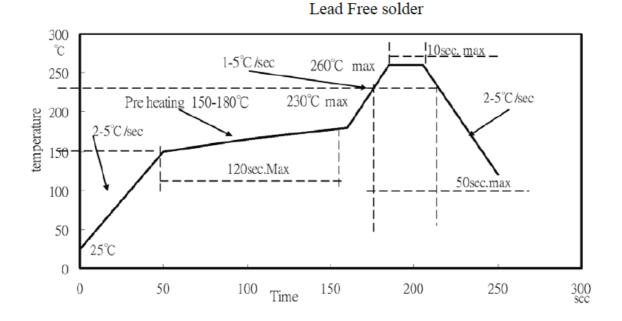
| INV | - | Р | 5 | 3 | С | Т | R | | IR | - | Х | х | Х | х |
|-----------------|---|------------------|-------|-----------|--------------|------------------|--------------|--------------------|------------|---|---|---|------------|---|
| | | Material | Pacl | kage | Variation | Orientation | Current | Lens | Color | | | | miz p-o | |
| Inolux VCSEL | | P = PLCC Type | 53C = | = 5.6 x 3 | .0, 120 Deg. | T = Top Mount | R = 200mA | (Blank) = Clear | IR = 850nm | | | | | |

Lot No.:

| Z | 2 | 0 | 1 | 7 | 01 | 24 | 001 |
|---------------|---|------------|----------|---|-------|------|--------|
| ernal cker | | Year (2017 | , 2018,) | | Month | Date | Serial |



Reflow Soldering



Soldering Iron

Basic Spec is ≤ 4 sec. when 260°C (+10°C \rightarrow -1 second). Power dissipation of Iron should be less than 15W. Surface temperature should be under 230°C

Rework

Rework should be completed within 4 second under 245°C

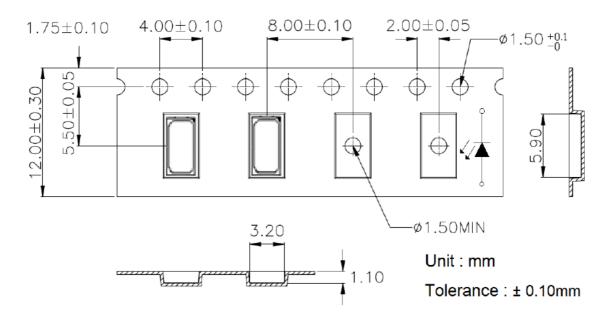
Notes

- 1. Do not stress the silicone resin while it is exposed to high temperature.
- 2. The number of reflow process should not exceed 3 times.

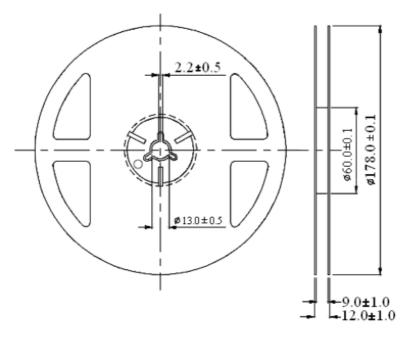


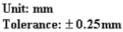
Packing

Carrier Tape Dimensions: Loaded quantity 3000pcs per reel.



Reel Dimensions:







Test Items and Results of Reliability

| Test Item | Test Conditions | Duration/ Cycle | Number of Damage | Reference |
|---------------------------------|------------------------------------|--------------------|---------------------|--------------------------------|
| Thermal Shock | –40℃ 30min 个↓5min 125℃ 30min | 100 cycles | 0/22 | AECQ101 |
| High Temperature Storage | Ta=100°C | 1000 hrs | 0/22 | EIAJ ED-4701 200 201 |
| Humidity Heat Storage | Ta=85℃ RH=85% | 1000 hrs | 0/22 | EIAJ ED-4701 100 103 |
| Low Temperature Storage | Ta=-40°C | 1000 hrs | 0/22 | EIAJ ED-4701 200 202 |
| Life Test | Ta=25℃ If=200mA | 1000 hrs | 0/22 | Tested with Inolux standard |
| High Humidity Heat Life Test | 85℃ RH=85% If=200mA | 1000 hrs | 0/22 | Tested with Inolux standard |
| High Temperature Life Test | Ta=85℃ | 1000 hrs | 0/22 | Tested with Inolux standard |
| ESD(HBM) | 2KV at 1.5kΩ;100pf | 3 Times | 0/22 | MIL-STD-883 |

| Criteria for Judging the Damage | | | | | | | | | |
|---------------------------------|--------------|-----------|-----------------------|-----------------------|--|--|--|--|--|
| litere | Currente a l | Condition | Criteria for Judgment | | | | | | |
| ltem | Symbol | Condition | Min | Max | | | | | |
| Forward Voltage | VF | If=200mA | - | USL ¹ ×1.1 | | | | | |
| Reverse Current | IR | VR =5V | - | 100µA | | | | | |
| Luminous Intensity | lv | If=200mA | LSL ² ×0.7 | - | | | | | |

Notes:

- 1. USL: Upper specification level
- 2. LSL: Lower specification level



Revision History

| Changes since last revision | Page | Version No. | Revision Date |
|----------------------------------|---------|-------------|----------------------|
| Initial Release | | 1.0 | 02-03-2019 |
| Update the Drawing and Parameter | 1,2,3,4 | 1.1 | 05-13-2019 |
| Update the Drawing | 1 | 1.2 | 03-05-2021 |
| | | | |
| | | | |
| | | | |
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